

Standard Rectifier	V _{RRM}	=	1600 V
	I _{FAV}	=	150 A
	V _F	=	1.05 V

Single Diode

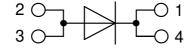
Part number

DMA150E1600NA



Backside: Isolated





Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase
- bridge configurations

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper
- internally DCB isolatedAdvanced power cycling

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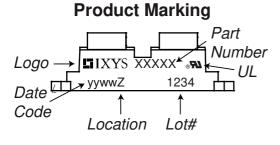
Rectifier					Rating	5	
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse bloc	king voltage	$T_{VJ} = 25^{\circ}C$			1700	V
V _{RRM}	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			1600	V
I _R	reverse current	$V_{R} = 1600 V$	$T_{VJ} = 25^{\circ}C$			200	μA
		$V_{R} = 1600 V$	$T_{vJ} = 150^{\circ}C$			3.5	mA
V _F	forward voltage drop	I _F = 150 A	$T_{VJ} = 25^{\circ}C$			1.15	V
		I _F = 300 A				1.36	V
		$I_{\rm F} = 150 \rm A$	T _{VJ} = 125 °C			1.05	V
		$I_{F} = 300 \text{ A}$				1.33	V
FAV	average forward current	T _c = 110°C	$T_{VJ} = 150 ^{\circ}\text{C}$			150	Α
		rectangular d = 0.5					1
V _{F0}	threshold voltage		$T_{vJ} = 150^{\circ}C$			0.78	V
r _F	slope resistance } for power	loss calculation only				1.8	mΩ
R _{thJC}	thermal resistance junction to ca	ase				0.2	K/W
R _{thCH}	thermal resistance case to heats	sink			0.1		K/W
P _{tot}	total power dissipation		$T_c = 25^{\circ}C$			620	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			3.00	kA
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			3.24	kA
		t = 10 ms; (50 Hz), sine	$T_{vJ} = 150^{\circ}C$			2.55	kA
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			2.76	kA
l²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			45.0	kA²s
		t = 8,3 ms; (60 Hz), sine	$V_{R} = 0 V$			43.7	kA²s
		t = 10 ms; (50 Hz), sine	T _{vJ} = 150°C			32.5	kA ² s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			31.6	kA²s
C	junction capacitance	V_{R} = 400 V; f = 1 MHz	$T_{vJ} = 25^{\circ}C$		60		pF

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Package	e SOT-227B (minibloc)				I	Rating	S	
Symbol	Definition	Conditions			min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal 1)					150	A
T _{vj}	virtual junction temperature				-40		150	°C
T _{op}	operation temperature				-40		125	°C
T _{stg}	storage temperature				-40		150	°C
Weight						30		g
M _D	mounting torque				1.1		1.5	Nm
M _T	terminal torque				1.1		1.5	Nm
d _{Spp/App}	oroonago distanco on surface	e striking distance through air	terminal to terminal	10.5	3.2			mm
d _{Spb/Apb}	creepage ustance on surface	sinking distance through an	terminal to backside	8.6	6.8			mm
V	isolation voltage	t = 1 second			3000			V
	t = 1 minute		50/60 Hz, RMS; lıso∟ ≤ 1 mA		2500			V

¹⁾ I_{must} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.



Part description

- D = Diode
- M = Standard Rectifier
- A = (up to 1800V)
- 150 = Current Rating [A]
- E = Single Diode 1600 = Reverse Voltage [V]
- NA = SOT-227B (minibloc)

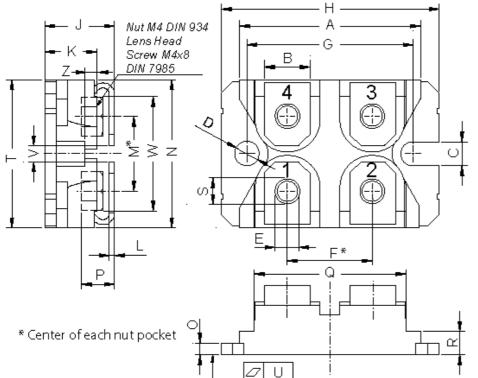
Standard DMA150E1600NA DMA150E1600NA Tube 10 508942	Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
	Standard	DMA150E1600NA	DMA150E1600NA	Tube	10	508942

Equiva	lent Circuits for	Simulation	* on die level	$T_{VJ} = 150^{\circ}C$
	- R o -	Rectifier		
V _{0 max}	threshold voltage	0.78		V
$\mathbf{R}_{0 \text{ max}}$	slope resistance *	1		mΩ

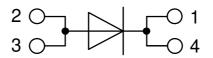
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Outlines SOT-227B (minibloc)



Dim.	Millimeter		Inches		
Dim.	min	max	min	max	
Α	31.50	31.88	1.240	1.255	
В	7.80	8.20	0.307	0.323	
С	4.09	4.29	0.161	0.169	
D	4.09	4.29	0.161	0.169	
Е	4.09	4.29	0.161	0.169	
F	14.91	15.11	0.587	0.595	
G	30.12	30.30	1.186	1.193	
Н	37.80	38.23	1.488	1.505	
J	11.68	12.22	0.460	0.481	
К	8.92	9.60	0.351	0.378	
L	0.74	0.84	0.029	0.033	
Μ	12.50	13.10	0.492	0.516	
Ν	25.15	25.42	0.990	1.001	
0	1.95	2.13	0.077	0.084	
Р	4.95	6.20	0.195	0.244	
Q	26.54	26.90	1.045	1.059	
R	3.94	4.42	0.155	0.167	
S	4.55	4.85	0.179	0.191	
Т	24.59	25.25	0.968	0.994	
U	-0.05	0.10	-0.002	0.004	
V	3.20	5.50	0.126	0.217	
W	19.81	21.08	0.780	0.830	
Ζ	2.50	2.70	0.098	0.106	

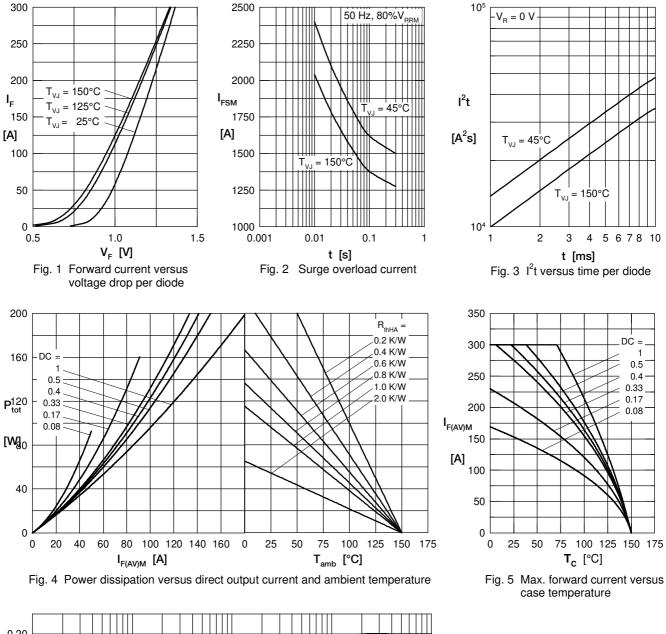


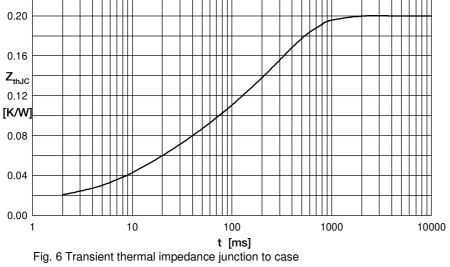
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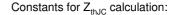
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Rectifier







i	R _{thi} (K/W)	t _i (s)
1	0.017	0.01
2	0.013	0.00001
3	0.010	0.01
4	0.04	0.04
5	0.12	0.3

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